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RV COLLEGE OF ENGINEERING
Autonomous Institution affiliated to VTU
II Semester B.E. 2023 Examinations
DEPTMEN OF PHYSICS
COURSE TITLE: Quantum Mechanics for Engineers.
(2022 SCHEME)
(Integrated Course – Lab + Theory)

Time: 03 Hours**Maximum Marks: 100****Instructions to candidates:**

Answer all questions from Part A. Part A questions should be answered in first three pages of the answer book only.

Answer FIVE full questions from Part B. In Part B question number 2 is compulsory. Answer any one full question from 3 and 4, 5 and 6, 7 and 8, and 9 and 10, and 11 lab components (compulsory).

Physical constants: $h = 6.625 \times 10^{-34} \text{Js}$, $m_e = 9.1 \times 10^{-31} \text{kg}$, $k_b = 1.38 \times 10^{-23} \text{J/K}$,

PART-A (Objective type for one or two marks)

(True & false and match the following questions are not permitted)

| | | | |
|---|-----|--|----|
| 1 | 1.1 | Discuss one property of wave function? | 10 |
| | 1.2 | Why can we not achieve population inversion under natural conditions? | |
| | 1.3 | Which type of attenuation is dependent on the wavelength? | |
| | 1.4 | What is Mathiesen's rule? | |
| | 1.5 | Discuss any one difference between type-I and II superconductor? | |
| | 1.6 | What is Josephson's effect? | |
| | 1.7 | Determine if the matrix given by $A = \begin{bmatrix} 1 & i \\ -i & 1 \end{bmatrix}$ a.) Is it Hermitian? b.) Is it Unitary? | |
| | 1.8 | For Silicon at 30°C, calculate the number of states per unit energy per unit volume at an energy 26 meV above the bottom of the conduction band ($m_e^* = 1.18 m_e$) | |

PART-B (Maximum subdivisions is limited to 2 in each question)

| UNIT-I | | | |
|---------|---|--|-----|
| 2 | a | Starting with the classical wave equation derive an expression for Time Independent Schrodinger equation? Write the energy operator using the TISE equation. | 7+7 |
| | b | For a particle trapped in an infinite potential well, with a neat figure derive the energy eigenvalue and sketch the probability density for the second excited states, clearly stating the maximum and minimum. | |
| UNIT-II | | | |
| 3 | a | What are Qubits? With a neat figure describe single particle quantum interference. | |
| | b | $a = \begin{bmatrix} 2i \\ 3 + 3i \\ -i \end{bmatrix}$ If $\begin{bmatrix} 2i \\ 3 + 3i \\ -i \end{bmatrix}$, compute $\langle a, a \rangle$ | |

| | | | |
|---|---|---|-----|
| | | <p>The Pauli matrices are given as</p> $A = \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix}, \quad B = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}, \quad C = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$ <p>i) Show that $A^2=B^2=C^2=I$ ii) Show that any of the two matrices anti-commute.</p> | 7+7 |
| | | OR | |
| 4 | a | Discuss the various single qubit gates in detail. | |
| | b | With a neat figure explain the principle, construction and result of the single photon experiment | |

| UNIT-III | | | |
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| 5 | a | <p>A rectangular plate of semiconductor is subjected to a current of 4 mA along the X-direction, a magnetic field of 2 Tesla along the Z-direction. This result in a potential difference of 2 mV being developed parallel to the XZ- plane. If the plate has dimensions of 4 cm along X- direction, 2.0 cm along Y-direction, and 2.0 mm along Z-direction. Calculate the Hall coefficient of the material and its charge carrier concentration.</p> <p>Sketch the variation of Fermi energy level with respect to concentration for an n-type semiconductor.</p> | 7+7 |
| | b | Derive an expression for the concentration of electrons in the conduction band for an intrinsic semiconductor. | |
| | | OR | |
| 6 | a | <p>Sketch the variation of Fermi factor for zero and non-zero temperature. Define the definition of Fermi energy valid at all temperatures.</p> <p>The Fermi energy for copper is 7.0 eV. For copper at 827°C, determine the energy of the electron level for which the probability of occupation is 0.95</p> | 7+7 |
| | b | What is carrier concentration? Derive an expression for the carrier concentration in a p-type semiconductor under the influence of a mutually perpendicular EXB fields. | |

| UNIT-IV | | | |
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| 7 | A | <p>What is an optical fiber? Explain the propagation of light in an optical condition. Obtain an expression for the numerical aperture of an optical fiber.</p> <p>The acceptance angle of an optical fiber is 30° and the fractional index change is 0.0505. Calculate the refractive indices of the core and cladding.</p> | 7+7 |
| | B | What are the requisites of laser? Explain the working with a neat energy diagram for Semiconductor laser. | |
| | | OR | |
| 8 | a | <p>Discuss the Graded refractive index fiber with the help of neat figure and specifically explain the variation of R.I with respect to radial distances.</p> <p>An optic fiber of RI 1.50 is to be clad to ensure TIR that will contain light travelling within 5° of the fiber axis. What minimum RI is allowed for the cladding? If the core diameter is 40 μm and the wavelength of light</p> | 7+7 |

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| | | propagating is 1400 nm. Calculate its V-number and number of modes? | |
| | b | Explain the three types of interactions between the radiation and matter. Obtain an expression for the energy density of radiation in terms of Einstein's coefficients. | |

| UNIT-V | | | |
|--------|---|--|-----|
| 9 | a | Discuss AC and DC Josephson effect in detail | 7+7 |
| | b | Discuss in detail DC Squids. How are Squids useful in quantum computing? | |
| | | OR | |
| 10 | a | Explain BCS theory in detail. | 7+7 |
| | b | Define Meissner effect and discuss its application of Meissner effect in Maglev trains. Discuss in brief about critical current. | |

| LAB COMPONENT | | | | | | | | | | | | | | | |
|---------------------|---|---|-------------------|------|------|------|---|-------|---|---|---------------------|---|-----|-----|------|
| 11 | a | What is a transistor? Draw a neat labeled diagram of a transistor circuit and the model graph(s). Explain the procedure to obtain the output characteristics of the transistor. From the model graph(s) show that the transistor can be used as a voltage and current regulator. | | | | | | 10+10 | | | | | | | |
| | b | With a neat figure, describe the apparatus required and procedure for conduction of the wavelength of laser experiment. If the distance between the grating and screen is 1 meter and the diffraction order is given below. The grating constant is $5.08 \times 10^{-5} \text{m}$. What is the wavelength and color of the laser generated? | | | | | | | | | | | | | |
| | | <table><tr><td>Diffraction order</td><td>1</td><td>2</td><td>3</td><td>4</td><td>5</td><td>6</td></tr><tr><td>Distance ($2X_n$)</td><td>3</td><td>5.8</td><td>8.7</td><td>11.5</td><td>14.4</td><td>17.2</td></tr></table> | Diffraction order | 1 | 2 | 3 | 4 | | 5 | 6 | Distance ($2X_n$) | 3 | 5.8 | 8.7 | 11.5 |
| Diffraction order | 1 | 2 | 3 | 4 | 5 | 6 | | | | | | | | | |
| Distance ($2X_n$) | 3 | 5.8 | 8.7 | 11.5 | 14.4 | 17.2 | | | | | | | | | |